

## Lecture 21

### OUTLINE

- Frequency Response
  - Review of basic concepts
  - high-frequency MOSFET model
  - CS stage
  - CG stage
  - Source follower
  - Cascode stage
- Reading: Chapter 11

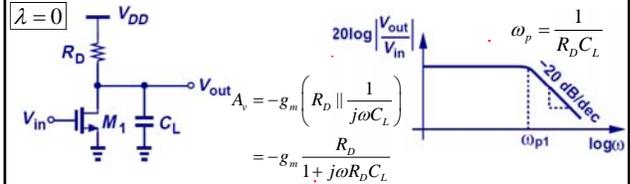
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## $A_v$ Roll-Off due to $C_L$

- The impedance of  $C_L$  decreases at high frequencies, so that it shunts some of the output current to ground.



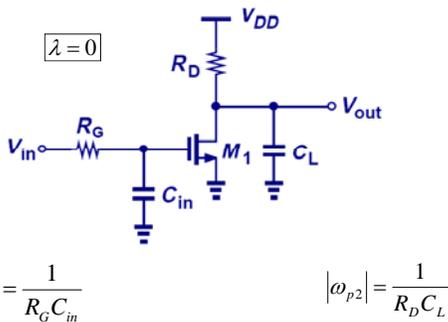
- In general, if **node  $j$  in the signal path** has a small-signal resistance of  $R_j$  to ground and a capacitance  $C_j$  to ground, then it contributes a **pole at frequency  $(R_j C_j)^{-1}$**

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## Pole Identification Example 1

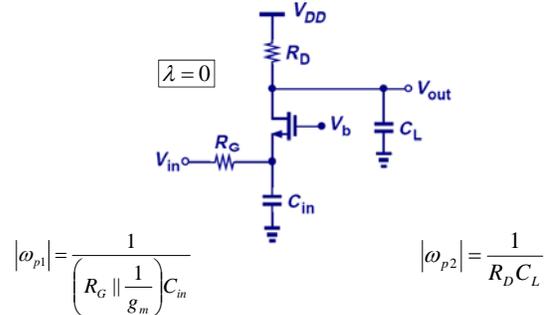


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## Pole Identification Example 2



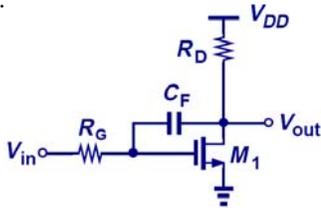
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### Dealing with a Floating Capacitance

- Recall that a pole is computed by finding the resistance and capacitance between a node and (AC) GROUND.
- It is not straightforward to compute the pole due to  $C_F$  in the circuit below, because neither of its terminals is grounded.



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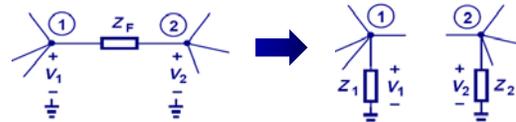
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### Miller's Theorem

- If  $A_v$  is the voltage gain from node 1 to 2, then a floating impedance  $Z_F$  can be converted to two grounded impedances  $Z_1$  and  $Z_2$ :

$$\frac{V_1 - V_2}{Z_F} = \frac{V_1}{Z_1} \Rightarrow Z_1 = Z_F \frac{V_1}{V_1 - V_2} = Z_F \frac{1}{1 - A_v}$$



$$\frac{V_1 - V_2}{Z_F} = -\frac{V_2}{Z_2} \Rightarrow Z_2 = -Z_F \frac{V_2}{V_1 - V_2} = Z_F \frac{1}{1 - 1/A_v}$$

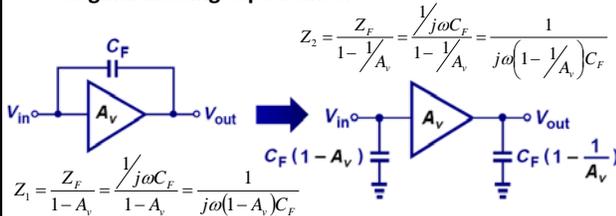
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### Miller Multiplication

- Applying Miller's theorem, we can convert a floating capacitance between the input and output nodes of an amplifier into two grounded capacitances.
- The capacitance at the input node is larger than the original floating capacitance.

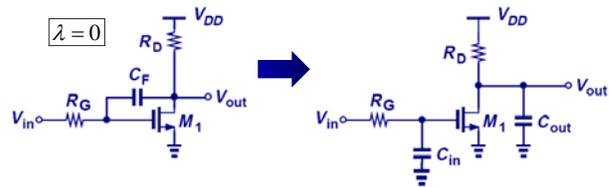


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### Application of Miller's Theorem



$$\omega_{in} = \frac{1}{R_G(1 + g_m R_D)C_F}$$

$$\omega_{out} = \frac{1}{R_D \left(1 + \frac{1}{g_m R_D}\right) C_F}$$

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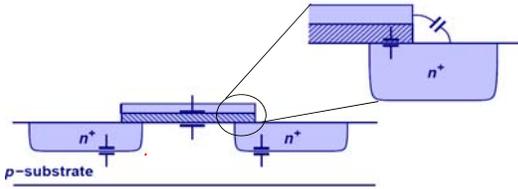
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### MOSFET Intrinsic Capacitances

The MOSFET has intrinsic capacitances which affect its performance at high frequencies:

1. gate oxide capacitance between the gate and channel,
2. overlap and fringing capacitances between the gate and the source/drain regions, and
3. source-bulk & drain-bulk junction capacitances ( $C_{SB}$  &  $C_{DB}$ ).

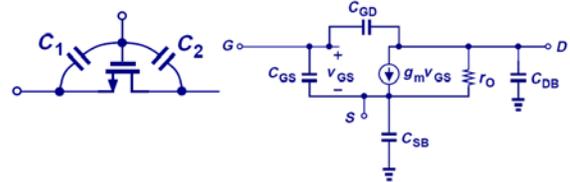


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### High-Frequency MOSFET Model

- The gate oxide capacitance can be decomposed into a capacitance between the gate and the source ( $C_1$ ) and a capacitance between the gate and the drain ( $C_2$ ).

- In saturation,  $C_1 \cong (2/3) \times C_{gate}$ , and  $C_2 \cong 0$ . ( $C_{gate} = C_{ox}WL$ )
- $C_1$  in parallel with the source overlap/fringing capacitance  $\rightarrow C_{GS}$
- $C_2$  in parallel with the drain overlap/fringing capacitance  $\rightarrow C_{GD}$



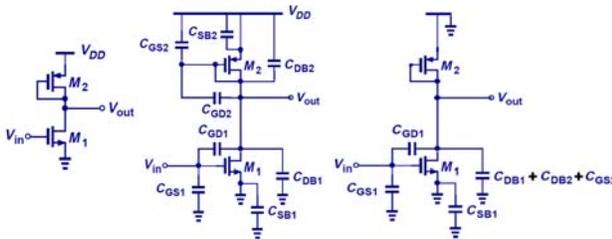
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### Example

**CS stage**

...with MOSFET capacitances explicitly shown

Simplified circuit for high-frequency analysis

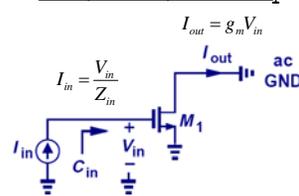


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### Transit Frequency

- The "transit" or "cut-off" frequency,  $f_T$ , is a measure of the intrinsic speed of a transistor, and is defined as the frequency where the current gain falls to 1.

Conceptual set-up to measure  $f_T$



$$\left| \frac{I_{out}}{I_{in}} \right| = |g_m Z_{in}| = \left| g_m \left( \frac{1}{j\omega C_{in}} \right) \right| = 1$$

$$\Rightarrow \omega_T = \frac{g_m}{C_{in}}$$

$$2\pi f_T = \frac{g_m}{C_{GS}}$$

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### Small-Signal Model for CS Stage

$\lambda = 0$

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### ... Applying Miller's Theorem

$$V_{Thev} = V_{in}$$

$$R_{Thev} = R_G$$

$$C_X = C_{GD} (1 + g_m R_D)$$

$$C_Y = C_{GD} \left(1 + \frac{1}{g_m R_D}\right)$$

$$\omega_{p,in} = \frac{1}{R_{Thev} (C_{in} + (1 + g_m R_D) C_{GD})}$$

$$\omega_{p,out} = \frac{1}{R_D \left(C_{out} + \left(1 + \frac{1}{g_m R_D}\right) C_{GD}\right)}$$

**Note that  $\omega_{p,out} > \omega_{p,in}$**

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### Direct Analysis of CS Stage

- Direct analysis yields slightly different pole locations and an extra zero:

$$\omega_z = \frac{g_m}{C_{XY}}$$

$$\omega_{p1} = \frac{1}{(1 + g_m R_D) C_{XY} R_{Thev} + R_{Thev} C_{in} + R_D (C_{XY} + C_{out})}$$

$$\omega_{p2} = \frac{(1 + g_m R_D) C_{XY} R_{Thev} + R_{Thev} C_{in} + R_D (C_{XY} + C_{out})}{R_{Thev} R_D (C_{in} C_{XY} + C_{out} C_{XY} + C_{in} C_{out})}$$

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### I/O Impedances of CS Stage

$\lambda = 0$

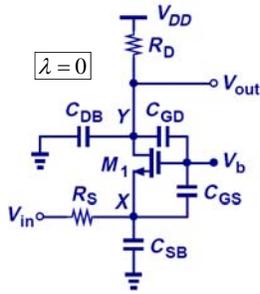
$$Z_{in} \approx \frac{1}{j\omega [C_{GS} + (1 + g_m R_D) C_{GD}]}$$

$$Z_{out} = \frac{1}{j\omega [C_{GD} + C_{DB}]} \parallel R_D$$

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### CG Stage: Pole Frequencies

CG stage with MOSFET capacitances shown



$$\omega_{p,X} = \frac{1}{\left(R_S \parallel \frac{1}{g_m}\right) C_X}$$

$$C_X = C_{GS} + C_{SB}$$

$$\omega_{p,Y} = \frac{1}{R_D C_Y}$$

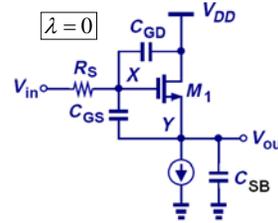
$$C_Y = C_{GD} + C_{DB}$$

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### AC Analysis of Source Follower



- The transfer function of a source follower can be obtained by direct AC analysis, similarly as for the emitter follower

$$\frac{v_{out}}{v_{in}} = \frac{1 + (j\omega) \frac{C_{GS}}{g_m}}{a(j\omega)^2 + b(j\omega) + 1}$$

$$a = \frac{R_S}{g_m} (C_{GD} C_{GS} + C_{GD} C_{SB} + C_{GS} C_{SB})$$

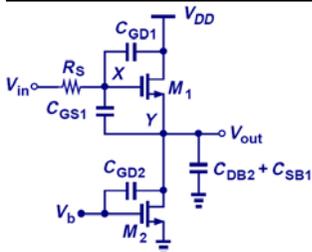
$$b = R_S C_{GD} + \frac{C_{GD} + C_{SB}}{g_m}$$

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### Example



$$\frac{v_{out}}{v_{in}} = \frac{1 + (j\omega) \frac{C_{GS}}{g_m}}{a(j\omega)^2 + b(j\omega) + 1}$$

$$a = \frac{R_S}{g_{m1}} [C_{GD1} C_{GS1} + (C_{GD1} + C_{GS1})(C_{SB1} + C_{GD2} + C_{DB2})]$$

$$b = R_S C_{GD1} + \frac{C_{GD1} + C_{SB1} + C_{GD2} + C_{DB2}}{g_{m1}}$$

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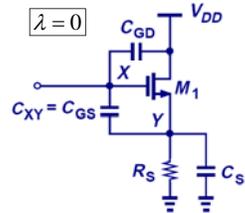
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### Source Follower: Input Capacitance

- Recall that the voltage gain of a source follower is  $A_v = \frac{R_S}{\frac{1}{g_m} + R_S}$

Follower stage with MOSFET capacitances shown



- $C_{XY}$  can be decomposed into  $C_X$  and  $C_Y$  at the input and output nodes, respectively:

$$C_X = (1 - A_v) C_{GS} = \frac{C_{GS}}{1 + g_m R_S}$$

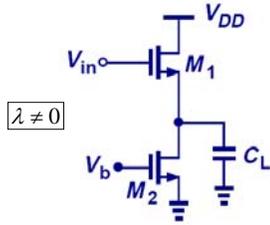
$$C_{in} = C_{GD} + \frac{C_{GS}}{1 + g_m R_S}$$

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### Example



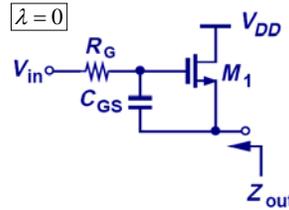
$$C_{in} = C_{GD1} + \frac{1}{1 + g_{m1}(r_{O1} \parallel r_{O2})} C_{GS1}$$

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### Source Follower: Output Impedance



- The output impedance of a source follower can be obtained by direct AC analysis of small-signal model, similarly as for the emitter follower

$$\frac{v_X}{i_X} = \frac{j\omega R_G C_{GS} + 1}{j\omega C_{GS} + g_m}$$

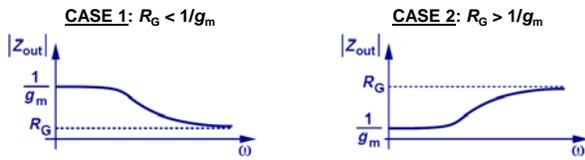
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### Source Follower as Active Inductor

$$Z_{out} = \frac{j\omega R_G C_{GS} + 1}{j\omega C_{GS} + g_m}$$



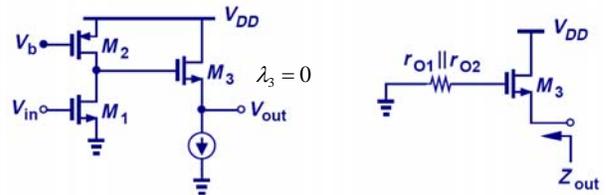
- A follower is typically used to lower the driving impedance, i.e.  $R_G$  is large compared to  $1/g_m$ , so that the "active inductor" characteristic on the right is usually observed.

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### Example



$$Z_{out} = \frac{j\omega(r_{O1} \parallel r_{O2})C_{GS3} + 1}{j\omega C_{GS3} + g_{m3}}$$

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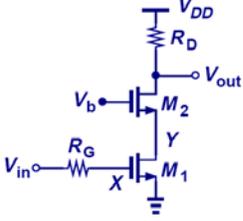
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### MOS Cascode Stage

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- For a cascode stage, Miller multiplication is smaller than in the CS stage.



$$A_{v,XY} \equiv \frac{v_X}{v_Y} = -g_{m1} \left( \frac{1}{g_{m2}} \right) \approx -1$$

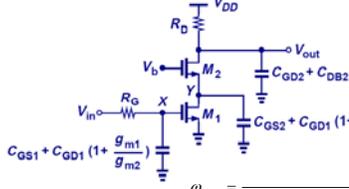
$$\Rightarrow C_X \approx 2C_{XY}$$

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### Cascode Stage: Pole Frequencies

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$\lambda = 0$       Cascode stage with MOSFET capacitances shown  
(Miller approximation applied)



$$\omega_{p,out} = \frac{1}{R_D(C_{DB2} + C_{GD2})}$$

$$\omega_{p,Y} = \frac{1}{\frac{1}{g_{m2}} \left[ C_{DB1} + C_{GS2} + \left( 1 + \frac{g_{m2}}{g_{m1}} \right) C_{GD1} + C_{SB2} \right]}$$

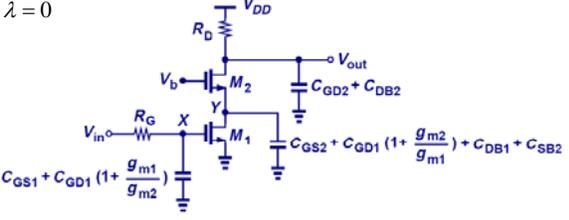
$$\omega_{p,X} = \frac{1}{R_G \left[ C_{GS1} + \left( 1 + \frac{g_{m1}}{g_{m2}} \right) C_{GD1} \right]}$$

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### Cascode Stage: I/O Impedances

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$\lambda = 0$



$$Z_{in} = \frac{1}{j\omega \left[ C_{GS1} + \left( 1 + \frac{g_{m1}}{g_{m2}} \right) C_{GD1} \right]}$$

$$Z_{out} = R_D \parallel \frac{1}{j\omega(C_{GD2} + C_{DB2})}$$

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